

LMP8640/LMP8640HV

Precision High Voltage Current Sense Amplifier

General Description

The LMP8640 and the LMP8640HV are precision current sense amplifiers that detect small differential voltages across a sense resistor in the presence of high input common mode voltages with a supply voltage range from 2.7V to 12V.

The LMP8640 accepts input signals with common mode voltage range from -2V to 42V, while the LMP8640HV accepts input signal with common mode voltage range from -2V to 76V. The LMP8640 and LMP8640HV have fixed gain for applications that demand accuracy over temperature. The LMP8640 and LMP8640HV come out with three different fixed gains 20V/V, 50V/V, 100V/V ensuring a gain accuracy as low as 0.25%. The output is buffered in order to provide low output impedance. This high side current sense amplifier is ideal for sensing and monitoring currents in DC or battery powered systems, excellent AC and DC specifications over temperature, and keeps errors in the current sense loop to a minimum. The LMP8640 and LMP8640HV are ideal choice for industrial, automotive and consumer applications, and it is available in TSOT-6 package.

Features

Typical values, $T_{\Delta} = 25^{\circ}C$

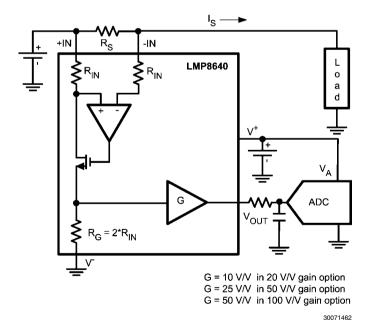
■ High common-mode voltage range

LMP8640 -2V to 42V _ LMP8640HV -2V to 76V Supply voltage range 2.7V to 12V 20V/V; 50V/V; 100V/V Gain options Max gain error 0.25% Low offset voltage 900µV Input bias current 13 µA 85 dB **PSRR** CMRR (2.1V to 42V) 103 dB -40°C to 125°C Temperature range 6-Pin TSOT Package

Applications

- High-side current sense
- Vehicle current measurement
- Motor controls
- Battery monitoring
- Remote sensing
- Power management

Typical Application



LMP™ is a trademark of National Semiconductor Corporation.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

ESD Tolerance (Note 2) **Human Body Model** For input pins +IN, -IN 5000V For all other pins 2000V Machine Model 200V Charge device model 1250V Supply Voltage (V_S = V⁺ - V⁻) 13.2V Differential Voltage +IN- (-IN) 6V Voltage at pins +IN, -IN LMP8640HV -6V to 80V LMP8640 -6V to 60V

Voltage at V_{OUT} pin V- to V+

Storage Temperature Range -65°C to 150°C

Junction Temperature (*Note 3*) 150°C

For soldering specifications,
see product folder at www.national.com and
www.national.com/ms/MS/MS-SOLDERING.pdf

Operating Ratings (Note 1)

Supply Voltage ($V_S = V^+ - V^-$) 2.7V to 12V Temperature Range (*Note 3*) -40°C to 125°C Package Thermal Resistance(*Note 3*)

TSOT-6 96°C/W

2.7V Electrical Characteristics (Note 4)

Unless otherwise specified, all limits guaranteed for at $T_A = 25^{\circ}C$, $V_S = V^+ - V^-$, $V_{SENSE} = +IN-(-IN)$, $V^+ = 2.7V$, $V^- = 0V$, $-2V < V_{CM} < 76V$, $R_1 = 10M\Omega$. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Condition	Min (<i>Note 6</i>)	Typ (<i>Note 5</i>)	Max (<i>Note 6</i>)	Units
V _{os}	Input Offset Voltage	V _{CM} = 2.1V	-900 -1160		900 1160	μV
TCV _{OS}	Input Offset Voltage Drift (Note 7, Note 9)	V _{CM} = 2.1V			2.6	μV/°C
I _B	Input Bias Current (Note 10)	V _{CM} = 2.1V		12	20 27	μΑ
e _{ni}	Input Voltage Noise (Note 9)	f > 10 kHz		117		nV/√Hz
Gain A _V	Fixed Gain LMP8640-T LMP8640HV-T			20		V/V
	Fixed Gain LMP8640-F LMP8640HV-F			50		V/V
	Fixed Gain LMP8640-H LMP8640HV-H			100		V/V
	Gain error	V _{CM} = 2.1V	-0.25 -0.51		0.25 0.51	%
	Accuracy over temperature (Note 9)	-40°C to 125°C, V _{CM} =2.1V			26.2	ppm/°C
PSRR	Power Supply Rejection Ratio	V _{CM} = 2.1V, 2.7V < V ⁺ < 12V,	85			dB
CMRR	Common Mode Rejection Ratio	LMP8640HV $2.1V < V_{CM} < 42V$ LMP8640 $2.1V < V_{CM} < 42V$	103			
		LMP8640HV 2.1V < V _{CM} < 76V	95			dB
		-2V <v<sub>CM < 2V,</v<sub>	60			
BW	Fixed Gain LMP8640-T LMP8640HV-T (<i>Note 9</i>)	DC $V_{SENSE} = 67.5 \text{ mV},$ $C_L = 30 \text{ pF}, R_L = 1 \text{M}\Omega$		950		
	Fixed Gain LMP8640-F LMP8640HV-F (<i>Note 9</i>)	DC V_{SENSE} =27 mV, C_L = 30 pF, R_L = 1M Ω	7 mV, 450			kHz
	Fixed Gain LMP8640-H LMP8640HV-H (<i>Note 9</i>)	DC V_{SENSE} = 13.5 mV, C_L = 30 pF , R_L = 1M Ω		230		
SR	Slew Rate (Note 8, Note 9)	$\begin{split} & V_{\text{CM}} = & 5\text{V, C}_{\text{L}} = 30 \text{ pF, R}_{\text{L}} = 1\text{M}\Omega, \\ & \text{LMP8640-T LMP8640HV-T V}_{\text{SENSE}} = & 100\text{mVpp,} \\ & \text{LMP8640-F LMP8640HV-F V}_{\text{SENSE}} = & 40\text{mVpp,} \\ & \text{LMP8640-H LMP8640HV-H V}_{\text{SENSE}} = & 20\text{mVpp,} \end{split}$		1.4		V/µs

Symbol	Parameter	Condition	Min (Note 6)	Typ (Note 5)	Max (Note 6)	Units
R _{IN}	Differential Mode Input Impedance (Note 9)			5		kΩ
I _S	Supply Current	$V_{CM} = 2.1V$		420	600 800	
		$V_{CM} = -2V$		2000	2500 2750	μΑ
V _{OUT}	Maximum Output Voltage	V _{CM} = 2.1V	2.65			V
		LMP8640-T LMP8640HV-T V _{CM} = 2.1V			18.2	
Minimum Outpu	Minimum Output Voltage	LMP8640-F LMP8640HV-F $V_{CM} = 2.1V$			40	mV
		LMP8640-H LMP8640HV-H V _{CM} = 2.1V			80	
C _{LOAD}	Max Output Capacitance Load (Note 9)			30		pF

5V Electrical Characteristics (Note 4)

Unless otherwise specified, all limits guaranteed for at T_A = 25°C, V_S =V+ - V-, V_{SENSE} = +IN-(-IN), V+ = 5V, V- = 0V, -2V < V_{CM} < 76V, R_L = 10M Ω . **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Condition	Min (Note 6)	Typ (Note 5)	Max (Note 6)	Units	
V _{OS}	Input Offset Voltage	V _{CM} = 2.1V	-900 -1160		900 1160	μV	
TCV _{OS}	Input Offset Voltage Drift (Note 7, Note 9)	V _{CM} = 2.1V			2.6	μV/°C	
I _B	Input Bias Current (Note 10)	V _{CM} = 2.1V		13	21 28	μΑ	
e _{ni}	Input Voltage Noise (Note 9)	f > 10 kHz		117		nV/√Hz	
Gain A _V	Fixed Gain LMP8640-T LMP8640HV-T			20		V/V	
	Fixed Gain LMP8640-F LMP8640HV-F			50		V/V	
	Fixed Gain LMP8640-H LMP8640HV-H			100		V/V	
	Gain error	V _{CM} = 2.1V	-0.25 -0.51		0.25 0.51	%	
	Accuracy over temperature (Note 9)	-40°C to 125°C, V _{CM} =2.1V			26.2	ppm/°C	
PSRR	Power Supply Rejection Ratio	V _{CM} = 2.1V, 2.7V < V ⁺ < 12V,	85			dB	
CMRR	Common Mode Rejection Ratio	LMP8640HV 2.1V < V _{CM} < 42V LMP8640 2.1V < V _{CM} < 42V	103				
		LMP8640HV 2.1V < V _{CM} < 76V	95			dB	
		-2V <v<sub>CM < 2V,</v<sub>	60				
BW	Fixed Gain LMP8640-T LMP8640HV-T (<i>Note 9</i>)	DC V_{SENSE} = 67.5 mV, C_L = 30 pF , R_L = 1M Ω		950			
	Fixed Gain LMP8640-F LMP8640HV-F(<i>Note 9</i>)	DC V_{SENSE} =27 mV, C_L = 30 pF , R_L = 1M Ω		450		kHz	
	Fixed Gain LMP8640-H LMP8640HV-H(<i>Note 9</i>)	DC V_{SENSE} = 13.5 mV, C_L = 30 pF , R_L = 1M Ω		230			

Symbol	Parameter	Condition	Min (Note 6)	Typ (Note 5)	Max (<i>Note 6</i>)	Units
SR	Slew Rate (Note 8, Note 9)	V_{CM} =5V, C_{L} = 30 pF, R_{L} = 1M Ω , LMP8640-T LMP8640HV-T V_{SENSE} =200mVpp,		1.6		V/µs
		$\begin{split} & LMP8640\text{-F LMP8640HV-F V}_{SENSE} = & 80\text{mVpp}, \\ & LMP8640\text{-H LMP8640HV-H V}_{SENSE} = & 40\text{mVpp}, \end{split}$				
R _{IN}	Differential Mode Input Impedance (Note 9)			5		kΩ
I _S	Supply Current	V _{CM} = 2.1V		500	722 922	μΑ
		$V_{CM} = -2V$		2050	2500 2750	μΛ
	Maximum Output Voltage	V _{CM} = 2.1V	4.95			V
	Minimum Output Voltage	LMP8640-T LMP8640HV-T V _{CM} = 2.1V			18.2	
V _{OUT}		LMP8640-F LMP8640HV-F V _{CM} = 2.1V			40	mV
		LMP8640-H LMP8640HV-H V _{CM} = 2.1V			80	
C _{LOAD}	Max Output Capacitance Load (Note 9)			30		pF

12V Electrical Characteristics (Note 4)

Unless otherwise specified, all limits guaranteed for at $T_A = 25^{\circ}C$, $V_S = V^+ - V^-$, $V_{SENSE} = +IN-(-IN)$, $V^+ = 12V$, $V^- = 0V$, $-2V < V_{CM} < 76V$, $R_L = 10M\Omega$. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Condition	Min (Note 6)	Typ (Note 5)	Max (Note 6)	Units
V _{OS}	Input Offset Voltage	V _{CM} = 2.1V	-900 -1160		900 1160	μV
TCV _{OS}	Input Offset Voltage Drift (Note 7, Note 9)	V _{CM} = 2.1V			2.6	μV/°C
I _B	Input Bias Current (Note 10)	V _{CM} = 2.1V		13	22 28	μA
e _{ni}	Input Voltage Noise (Note 9)	f > 10 kHz		117		nV/√Hz
Gain A _V	Fixed Gain LMP8640-T LMP8640HV-T			20		V/V
	Fixed Gain LMP8640-F LMP8640HV-F			50		V/V
	Fixed Gain LMP8640-H LMP8640HV-H			100		V/V
	Gain error	V _{CM} = 2.1V	-0.25 -0.51		0.25 0.51	%
	Accuracy over temperature (Note 9)	-40°C to 125°C, V _{CM} =2.1V			26.2	ppm/°C
PSRR	Power Supply Rejection Ratio	V _{CM} = 2.1V, 2.7V < V ⁺ < 12V,	85			dB
CMRR	Common Mode Rejection Ratio	LMP8640HV 2.1V < V _{CM} < 42V LMP8640 2.1V < V _{CM} < 42V	103			
		LMP8640HV 2.1V < V _{CM} < 76V	95			dB
		-2V <v<sub>CM < 2V,</v<sub>	60			

Symbol	Parameter	Condition	Min (<i>Note 6</i>)	Typ (<i>Note 5</i>)	Max (<i>Note 6</i>)	Units	
BW	Fixed Gain LMP8640-T LMP8640HV-T (<i>Note 9</i>)	DC $V_{SENSE} = 67.5 \text{ mV},$ $C_L = 30 \text{ pF}, R_L = 1M\Omega$		950			
	Fixed Gain LMP8640-F LMP8640HV-F (<i>Note 9</i>)	DC V_{SENSE} =27 mV, C_L = 30 pF , R_L = 1M Ω		450		kHz	
	Fixed Gain LMP8640-H LMP8640HV-H (<i>Note 9</i>)	DC V_{SENSE} = 13.5 mV, C_L = 30 pF , R_L = 1M Ω		230			
SR	Slew Rate (Note 8, Note 9)	$\begin{split} & \text{V}_{\text{CM}} = & \text{5V}, \text{C}_{\text{L}} = 30 \text{pF}, \text{R}_{\text{L}} = 1 \text{M}\Omega, \\ & \text{LMP8640-T LMP8640HV-T V}_{\text{SENSE}} = & \text{500mVpp}, \\ & \text{LMP8640-F LMP8640HV-F V}_{\text{SENSE}} = & \text{200mVpp}, \\ & \text{LMP8640-H LMP8640HV-H V}_{\text{SENSE}} = & \text{100mVpp}, \end{split}$		1.8		V/µs	
R _{IN}	Differential Mode Input Impedance (Note 9)			5		kΩ	
I _S	Supply Current	V _{CM} = 2.1V		720	1050 1250	4	
		$V_{CM} = -2V$		2300	2800 3000	μA	
V _{OUT}	Maximum Output Voltage	V _{CM} = 2.1V	11.85			V	
		LMP8640-T LMP8640HV-T V _{CM} = 2.1V			18.2		
	Minimum Output Voltage	LMP8640-F LMP8640HV-F V _{CM} = 2.1V			40	mV	
		LMP8640-H LMP8640HV-H V _{CM} = 2.1V			80		
C _{LOAD}	Max Output Capacitance Load (Note 9)			30		pF	

Note 1: "Absolute Maximum Ratings" indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the Absolute Maximum Ratings or other conditions beyond those indicated in the Operating Ratings is not implied. Operating Ratings indicate conditions at which the device is functional and the device should not be operated beyond such conditions.

Note 2: Human Body Model, applicable std. MIL-STD-883, Method 3015.7. Machine Model, applicable std. JESD22-A115-A (ESD MM std. of JEDEC) Field-Induced Charge-Device Model, applicable std. JESD22-C101-C (ESD FICDM std. of JEDEC).

Note 3: The maximum power dissipation must be derated at elevated temperatures and is dictated by $T_{J(MAX)}$, θ_{JA} , and the ambient temperature, T_A . The maximum allowable power dissipation $P_{DMAX} = (T_{J(MAX)} - T_A) / \theta_{JA}$ or the number given in Absolute Maximum Ratings, whichever is lower.

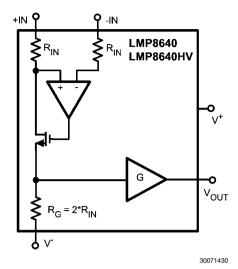
Note 4: Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No guarantee of parametric performance is indicated in the electrical tables under conditions of internal self-heating where $T_J > T_A$. Absolute Maximum Ratings indicate junction temperature limits beyond which the device may be permanently degraded, either mechanically or electrically.

Note 5: Typical values represent the most likely parametric norm at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.

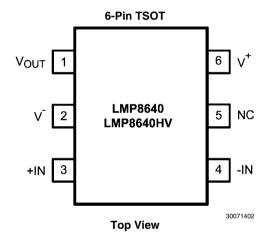
Note 6: Limits are 100% production tested at 25°C. Limits over the operating temperature range are guaranteed through correlations using statistical quality control (SQC) method.

- Note 7: Offset voltage temperature drift is determined by dividing the change in V_{OS} at the temperature extremes by the total temperature change.
- Note 8: The number specified is the average of rising and falling slew rates and measured at 90% to 10%.
- Note 9: This parameter is guaranteed by design and/or characterization and is not tested in production.
- Note 10: Positive Bias Current corresponds to current flowing into the device.

Block Diagram



Connection Diagram



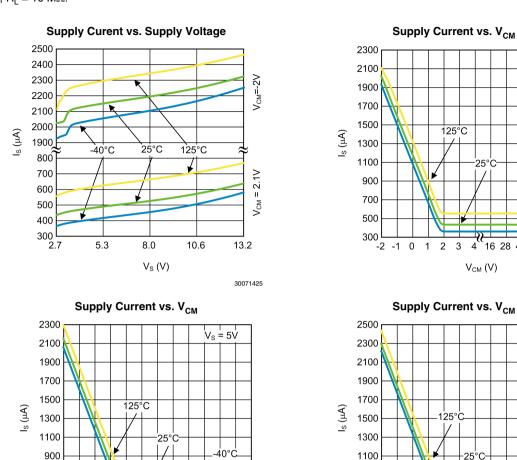
Pin Descriptions

Pin	Name	Description
1	V _{OUT}	Single Ended Output
2	V-	Negative Supply Voltage
3	+IN	Positive Input
4	-IN	Negative Input
5	NC	Not Connected
6	V+	Positive Supply Voltage

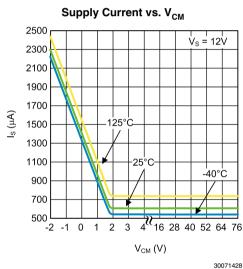
Ordering Information

Package	Gain	Part Number	Package Marking	Transport Media	NSC Drawing
		LMP8640MK-T		1k Units Tape and Reel	
		LMP8640MKE-T	AA6A	250 Units Tape and Reel	
C Din TCOT	00)///	LMP8640MKX-T		3k Units Tape and Reel	MICOCA
6-Pin TSOT	20V/V	LMP8640HVMK-T		1k Units Tape and Reel	MK06A
		LMP8640HVMKE-T	AB6A	250 Units Tape and Reel	
		LMP8640HVMKX-T		3k Units Tape and Reel	
		LMP8640MK-F		1k Units Tape and Reel	
		LMP8640MKE-F	AC6A	250 Units Tape and Reel	
	50V/V	LMP8640MKX-F		3k Units Tape and Reel	MICOCA
6-Pin TSOT		LMP8640HVMK-F		1k Units Tape and Reel	MK06A
		LMP8640HVMKE-F	AD6A	250 Units Tape and Reel	
		LMP8640HVMKX-F		3k Units Tape and Reel	
		LMP8640MK-H		1k Units Tape and Reel	
		LMP8640MKE-H	AE6A	250 Units Tape and Reel	
6 Din TOOT	100\///	LMP8640MKX-H	1	3k Units Tape and Reel	MKOEV
6-Pin TSOT	100V/V	LMP8640HVMK-H		1k Units Tape and Reel	MK06A
		LMP8640HVMKE-H	AF6A	250 Units Tape and Reel	
		LMP8640HVMKX-H	1	3k Units Tape and Reel	

Typical Performance Characteristics Unless otherwise specified: $T_A = 25^{\circ}C$, $V_S = V^+ - V^-$, $V_{SENSE} = +IN - (-IN)$, $R_L = 10 \text{ M}\Omega$.



16 28 40 52 64 76



125°C

2

 $V_{\text{CM}}\left(V\right)$

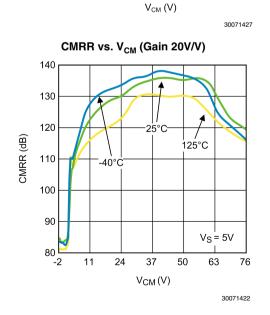
1

 $V_{\rm S} = 2.7 \rm V$

-40°C

30071426

16 28 40 52 64 76

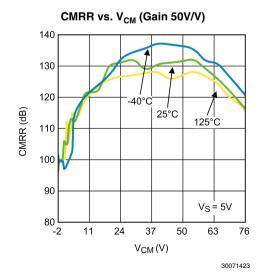


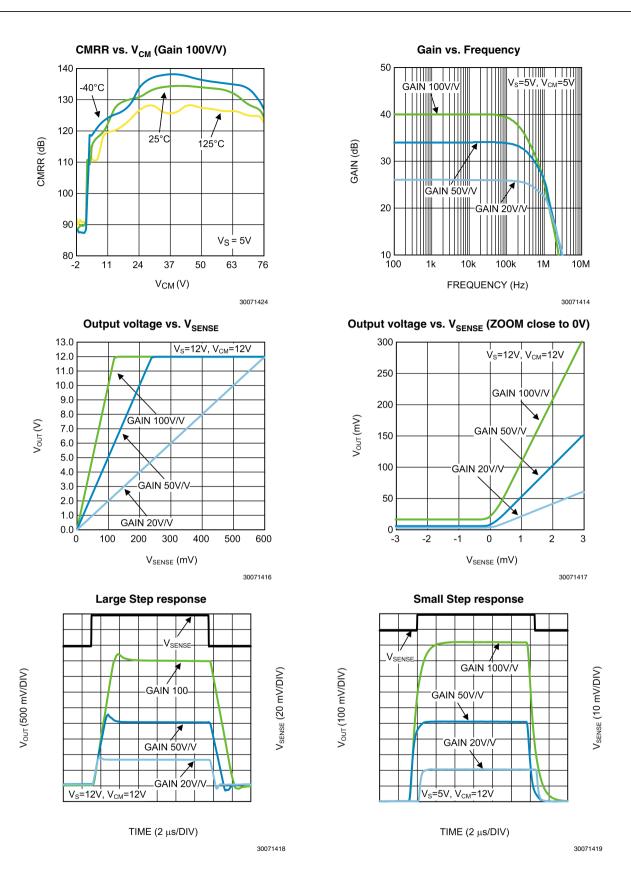
700

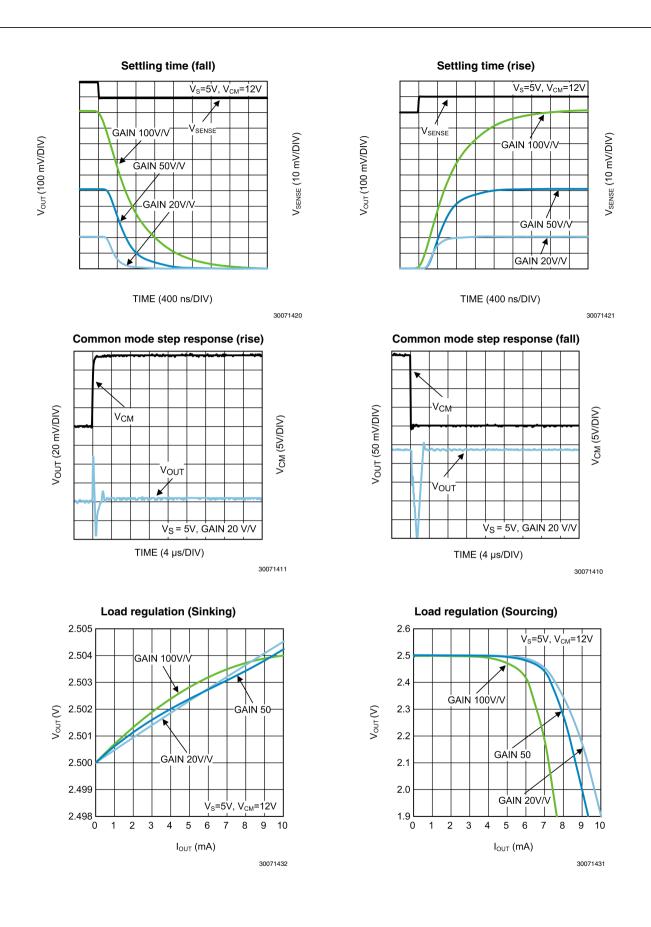
500

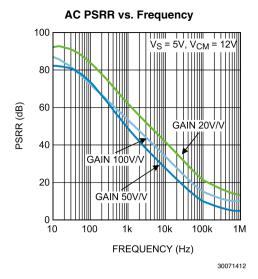
300

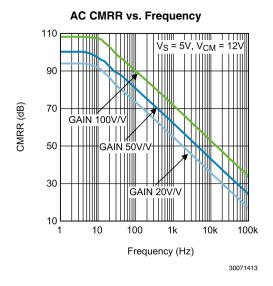
-2 -1 0 1 2 3











Application Information

GENERAL

The LMP8640 and LMP8640HV are single supply high side current sense amplifiers with a fixed gain of 20V/V, 50V/V, 100V/V and a common mode voltage range of -2V to 42V or -2V to 76V depending on the grade.

THEORY OF OPERATION

As seen from the picture below, the current flowing through $\rm R_S$ develops a voltage drop equal to $\rm V_{SENSE}$ across $\rm R_S$. The high impedance inputs of the amplifier doesn't conduct this current and the high open loop gain of the sense amplifier forces its non-inverting input to the same voltage as the inverting input. In this way the voltage drop across $\rm R_{IN}$ matches $\rm V_{SENSE}.$ A current proportional to $\rm I_S$ according to the following relation:

$$I_{G} = V_{SENSE}/R_{IN} = R_{S}^{*}I_{S}/R_{IN},$$

flows entirely in the internal gain resistor $\boldsymbol{R}_{\boldsymbol{G}}$ developing a voltage drop equal to

$$V_{RG} = I_{G} * R_{G} = (V_{SENSE}/R_{IN}) * R_{G} = ((R_{S} * I_{S})/R_{IN}) * R_{G}$$

This voltage is buffered and showed at the output with a very low impedance allowing a very easy interface of the LMP8640 with other ICs (ADC, μ C...).

$$V_{OUT} = 2*(R_S*I_S)*G,$$

where $G=R_G/R_{IN}$ = 10V/V, 25V/V, 50V/V, according to the gain options.

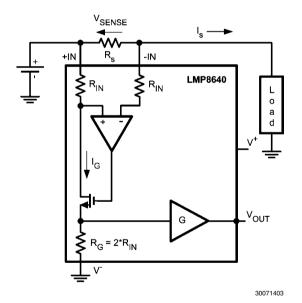


FIGURE 1. Current monitor

SELECTION OF THE SHUNT RESISTOR

The value chosen for the shunt resistor, $R_{\rm S}$, depends on the application. It plays a big role in a current sensing system and must be chosen with care. The selection of the shunt resistor needs to take in account the small-signal accuracy, the power dissipated and the voltage loss across the shunt itself. In applications where a small current is sensed, a bigger value of $R_{\rm S}$ is selected to minimize the error in the proportional output voltage. Higher resistor value improves the SNR at the input of the current sense amplifier and hence gives an accurate output. Similarly when high current is sensed, the power losses in $R_{\rm S}$ can be significant so a smaller value of $R_{\rm S}$ is sug-

gested. In this condition is required to take in account also the power rating of $\rm R_S$ resistor. The low input offset of the LMP8640 allows the use of small sense resistors to reduce power dissipation still providing a good input dynamic range. The input dynamic range is the ratio expressed in dB between the maximum signal that can be measured and the minimum signal that can be detected, usually the input offset is the principal limiting factor.

DRIVING ADC

The input stage of an Analog to Digital converter can be modelled with a resistor and a capacitance versus ground. So if the voltage source doesn't have a low impedance an error in the amplitude's measurement will occur. In this case a buffer is needed to drive the ADC. The LMP8640 has an internal output buffer able to drive a capacitance load up to 30 pF or the input stage of an ADC. If required an external low pass RC filter can be added at the output of the LMP8640 to reduce the noise and the bandwidth of the current sense.

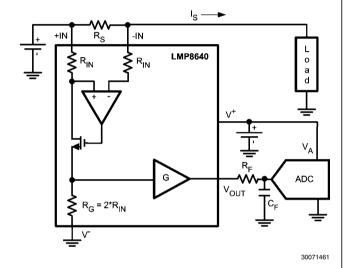


FIGURE 2. LMP8640 to ADC interface

DESIGN EXAMPLE

For example in a current monitor application is required to measure the current sunk by a load (peak current 10A) with a resolution of 10mA and 0.5% of accuracy. The 10bit analog to digital converter accepts a max input voltage of 4.1V. Moreover in order to not burn much power on the shunt resistor it needs to be less than $10 m\Omega.$ In the table below are summarized the other working condition.

Working Condition	Value		
	Min	Max	
Supply Voltage	5V	5.5V	
Common mode Voltage	48V	70V	
Temperature	0°C	70°C	
Signal BW		50kHz	

First step - LMP8640 / LMP8640HV selection

The required common mode voltage of the application implies that the right choice is the LMP8640HV (High common mode voltage up tp 76V).

Second step - Gain option selection

We can choose between three gain option (20V/V, 50V/V, 100V/V). considering the max input voltage of the ADC

(4.1V), the max Sense voltage across the shunt resistor is evaluated according the following formula:

V_{SENSE}= (MAX Vin ADC) / Gain;

hence the max $V_{\rm SENSE}$ will be 205mV, 82mV, 41mV respectively. The shunt resistor are then evaluated considering the maximum monitored current :

$$R_S = (max V_{SENSE}) / I_MAX$$

For each gain option the max shunt resistors are the following : $20.5m\Omega$, $8.2m\Omega$, $4.1m\Omega$ respectively.

One of the project constraints requires RS<10m Ω , it means that the 20.5m Ω will be discarded and hence the 50V/V and 100V/V gain options are still in play.

Third step - Shunt resistor selection

At this point an error budget calculation, considering the calibration of the Gain, Offset, CMRR, and PSRR, helps in the selection of the shunt resistor. In the table below the contribution of each error source is calculated considering the values of the EC Table at 5V supply.

Resolution Calculation

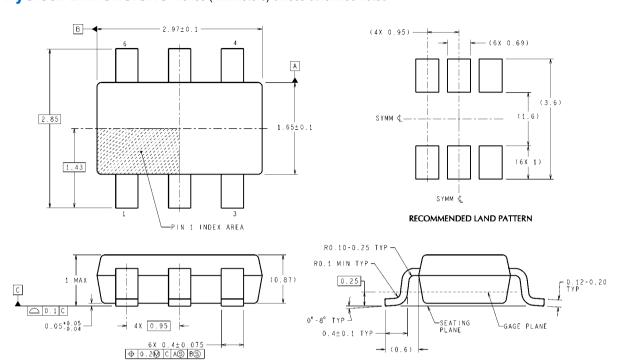
ERROR SOURCE	Rs=4.1mΩ	Rs=8.1mΩ
CMRR calibrated ad mid VCM range	77.9µV	77.9μV
PSRR calibrated at 5V	8.9µV	8.9µV
Total error (squared sum of contribution)	78µV	78µV
Resolution (Total error / R _S)	19.2mA	9.6mA

Accuracy Calculation

ERROR SOURCE	Rs=4.1mΩ	Rs=8.1mΩ
Tc Vos	182µV	182µV
Nosie	216µV	216µV
Gain drift	75.2µV	151µV
Total error (squared sum of contribution)	293µV	320µV
Accuracy 100*(Max_V _{SENSE} / Total Error)	0.7%	0.4%

From the tables above is clear that the $8.2m\Omega$ shunt resistor allows the respect of the project's constraints. The power burned on the Shunt is 820mW at 10A.

Physical Dimensions inches (millimeters) unless otherwise noted



DIMENSIONS ARE IN MILLIMETERS

MK06A (Rev E)

TSOT-6 NS Package Number MK06A

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Notes

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